QUAD/DUAL SUPERCAPACITOR AUTO BALANCING (SAB™) MOSFET ARRAY

GENERAL DESCRIPTION

The ALD810021/ALD910021 are members of the ALD8100xx (quad) and ALD9100xx (dual) family of Supercapacitor Auto Balancing MOSFETs, or SAB™ MOSFETs. SAB MOSFETs are built with production proven EPAD® technology and are designed to address voltage and leakage-current balancing of supercapacitors connected in series. Supercapacitors, also known as ultracapacitors or supercaps, connected in series can be leakage-current balanced by using a combination of one or more devices connected across each supercapacitor stack to prevent over-voltages.

The ALD810021 offers a set of unique, precise operating voltage and current characteristics for each of four SAB MOSFET devices, as shown in its Operating Electrical Characteristics table. It can be used to balance up to four supercapacitors connected in series. The ALD910021 has its own set of unique precision Operating Electrical Characteristics for each of its two SAB MOSFET devices, suitable for up to two series-connected supercapacitors.

Each SAB MOSFET features a precision gate threshold voltage in the V_t mode, which is 2.10V when the gate-drain source terminals ($V_{GS} = V_{DS}$) are connected together at a drain-source current of $I_{DS(ON)} = 1\mu A$. In this mode, input voltage $V_{IN} = V_{GS} = V_{DS}$. Different V_{IN} produces an Output Current $I_{OUT} = I_{DS(ON)}$ characteristic and results in an effective variable resistor that varies in value exponentially with V_{IN}. This V_{IN}, when connected across each supercapacitor in a series, balances each supercapacitor to within its voltage and current limits.

When V_{IN} = 2.10V is applied to an ALD810021/ALD910021, its I_{OUT} is 1μA. For a 100mV increase in V_{IN}, to 2.20V, I_{OUT} increases by about tenfold. For an additional increase in V_{IN} to 2.32V for the ALD910021 (2.34V for the ALD810021), I_{OUT} increases one hundredfold, to 100μA. Conversely, for a 100mV decrease in V_{IN} to 2.00V, I_{OUT} decreases to one tenth of its previous value, to 0.1μA. Another 100mV decrease in input voltage would reduce I_{OUT} to 0.01μA. Hence, when an ALD810021/ALD910021 SAB MOSFET is connected across a supercapacitor that charges to less than 1.90V, it would dissipate essentially no power.

(Continued on next page)

PRODUCT FAMILY SPECIFICATIONS

For more information on supercapacitor balancing, how SAB MOSFETs achieve automatic supercapacitor balancing, the device characteristics of the SAB MOSFET family, product family product selection guide, applications, configurations, and package information, please download from www.aldinc.com the document:

"ALD8100xx/ALD9100xx Family of Supercapacitor Auto Balancing (SAB™) MOSFET ARRAYs"

ORDERING INFORMATION ("L" suffix denotes lead-free (RoHS))

Package	Operating Temperature Range	
	0°C to +70°C (Commercial)	-40°C to +85°C (Industrial)
16-Pin SOIC	ALD810021SCL	ALD810021SCLI
8-Pin SOIC	ALD910021SAL	ALD910021SALI

FEATURES & BENEFITS

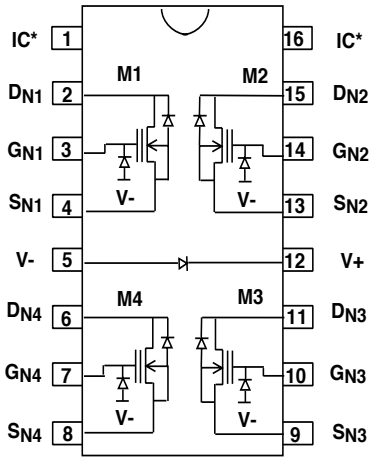
- Simple and economical to use
- Precision factory trimmed
- Automatically regulates and balances leakage currents
- Effective for supercapacitor charge-balancing
- Balances up to 4 supercaps with a single IC package
- Balances 2-cell, 3-cell, 4-cell series-connected supercaps
- Scalable to larger supercap stacks and arrays
- Near zero additional leakage currents
- Zero leakage at 0.3V below rated voltages
- Balances series and/or parallel-connected supercaps
- Leakage currents are exponential function of cell voltages
- Active current ranges from <0.3nA to >1000μA
- Always active, always fast response time
- Minimizes leakage currents and power dissipation

APPLICATIONS

- Series-connected supercapacitor cell leakage balancing
- Energy harvesting
- Long term backup battery with supercapacitor outputs
- Zero-power voltage divider at selected voltages
- Matched current mirrors and current sources
- Zero-power mode maximum voltage limiter
- Scaled supercapacitor stacks and arrays

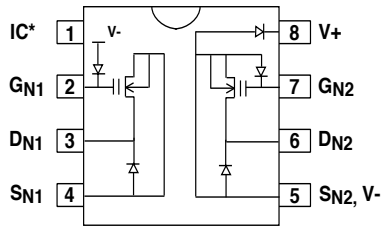
PIN CONFIGURATIONS

ALD810021



SCL PACKAGE

ALD910021



SAL PACKAGE

*IC pins are internally connected, connect to V-

GENERAL DESCRIPTION (CONT.)

The voltage dependent characteristic of the ALD810021/ ALD910021 on-resistance is effective in controlling excessive voltage rise across a supercapacitor when connected across it. In series-connected supercapacitor stacks, when one supercapacitor voltage rises, the voltage of the other supercapacitors drops, with the ones that have the highest leakage currents having the lowest supercapacitor voltages. The SAB MOSFETs connected across these supercapacitors would exhibit complementary opposing current levels, resulting in little additional leakage currents other than those caused by the supercapacitors themselves.

For technical assistance, please contact ALD technical support at techsupport@aldinc.com.

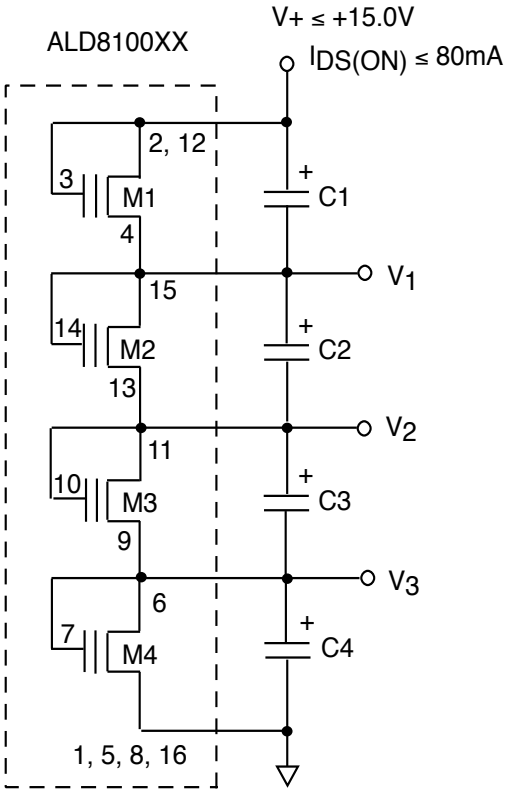
APPLYING THE ALD810021/ALD910021:

1) Select a maximum supercapacitor leakage current limit for any supercapacitor used in the stack. This is the same as output current, $I_{OUT} = I_{DS(ON)}$, of the ALD810021/ALD910021. Test that each supercapacitor leakage current meets this maximum current limit before use in the stack.

2) Determine whether the input voltage V_{IN} ($V_{GS} = V_{DS}$) at that I_{OUT} is acceptable for the intended application. This voltage is the same voltage as the maximum desired operating voltage of the supercapacitor. For example, with the ALD810021, $I_{OUT} = 1000\mu A$ corresponds to $V_{IN} = 2.62V$.

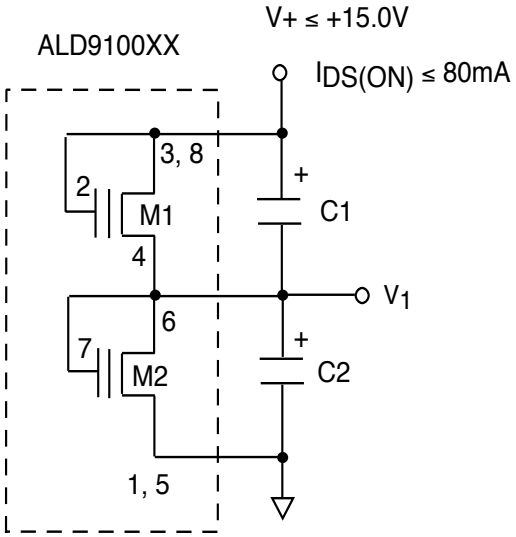
3) Determine that the operating voltage margin, due to various tolerances and/or temperature effects, is adequate for the intended operating environment of the supercapacitor.

SCHEMATIC DIAGRAM OF A TYPICAL
CONNECTION FOR A FOUR-SUPERCAP STACK



1-16 DENOTES PACKAGE PIN NUMBERS
C1-C4 DENOTES SUPERCAPACITORS

SCHEMATIC DIAGRAM OF A TYPICAL
CONNECTION FOR A TWO-SUPERCAP STACK



1-8 DENOTES PACKAGE PIN NUMBERS
C1-C2 DENOTES SUPERCAPACITORS

ABSOLUTE MAXIMUM RATINGS

V+ to V- voltage ____ 15.0V
Drain-Source voltage, V_{DS} ____ 10.6V
Gate-Source voltage, V_{GS} ____ 10.6V
Operating Current ____ 80mA
Power dissipation ____ 500mW
Operating temperature range SCL ____ 0°C to +70°C
Operating temperature range SCLI ____ -40°C to +85°C
Storage temperature range ____ -65°C to +150°C
Lead temperature, 10 seconds ____ +260°C

CAUTION: ESD Sensitive Device. Use static control procedures in ESD controlled environment.

OPERATING ELECTRICAL CHARACTERISTICS

V^+ = +5V, V^- = GND, T_A = 25°C, $V_{IN} = V_{GS} = V_{DS}$, $I_{OUT} = I_{DS(ON)}$ unless otherwise specified

Parameter	Symbol	ALD810021 Min	ALD810021 Typ	ALD810021 Max	Unit	Test Conditions
Gate Threshold Voltage	V_t	2.08	2.10	2.12	V	$V_{GS} = V_{DS}$; $I_{DS(ON)} = 1\mu A$
Offset Voltage	V_{OS}		5	20	mV	$V_{t1} - V_{t2}$ or $V_{t3} - V_{t4}$
Offset Voltage Tempco	TC_{VOS}		5		μV/C	$V_{t1} - V_{t2}$ or $V_{t3} - V_{t4}$
Gate Threshold Voltage Tempco	TC_{Vt}		-2.2		mV/C	$V_{GS} = V_{DS}$; $I_{DS(ON)} = 1\mu A$
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.0001 17000		μA MΩ	V_{IN} = 1.70V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.001 1800		μA MΩ	V_{IN} = 1.80V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.01 190		μA MΩ	V_{IN} = 1.90V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.1 20		μA MΩ	V_{IN} = 2.00V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		1 2.1		μA MΩ	V_{IN} = 2.10V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		10 0.22		μA MΩ	V_{IN} = 2.20V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		100 0.023		μA MΩ	V_{IN} = 2.34V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		300 0.008		μA MΩ	V_{IN} = 2.44V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		1000 0.003		μA MΩ	V_{IN} = 2.62V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		3000 0.001		μA MΩ	V_{IN} = 2.92V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		10000 0.0004		μA MΩ	V_{IN} = 3.52V
Drain Source Breakdown Voltage	BV_{DSX}	10.6			V	
Drain Source Leakage Current[1]	$I_{DS(OFF)}$		10	400 4	pA nA	$V_{IN} = V_{GS} = V_{DS} = V_t - 1.0$ $V_{IN} = V_{GS} = V_{DS} = V_t - 1.0$, T_A = +125°C
Gate Leakage Current[1]	I_{GSS}		5	200 1	pA nA	V_{GS} = 5.0V, V_{DS} = 0V V_{GS} = 5.0V, V_{DS} = 0V, T_A = +125°C
Input Capacitance	C_{ISS}		15		pF	V_{GS} = 0V, V_{DS} = 5.0V
Turn-on Delay Time	t_{on}		10		ns	
Turn-off Delay Time	t_{off}		10		ns	
Crosstalk			60		dB	f = 100KHz

ABSOLUTE MAXIMUM RATINGS

V+ to V- voltage 15.0V
Drain-Source voltage, V_{DS} 10.6V
Gate-Source voltage, V_{GS} 10.6V
Operating Current 80mA
Power dissipation 500mW
Operating temperature range SAL ..... 0°C to +70°C
Operating temperature range SALI ..... -40°C to +85°C
Storage temperature range ..... -65°C to +150°C
Lead temperature, 10 seconds ..... +260°C

CAUTION: ESD Sensitive Device. Use static control procedures in ESD controlled environment.

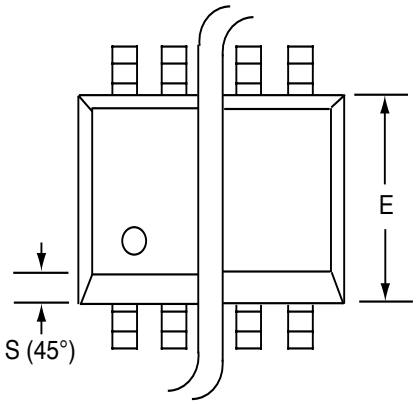
OPERATING ELECTRICAL CHARACTERISTICS

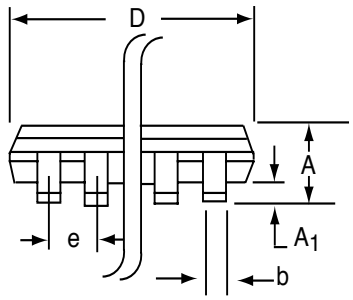
$V+ = +5V$, $V^- = GND$, $T_A = 25°C$, $V_{IN} = V_{GS} = V_{DS}$, $I_{OUT} = I_{DS(ON)}$ unless otherwise specified

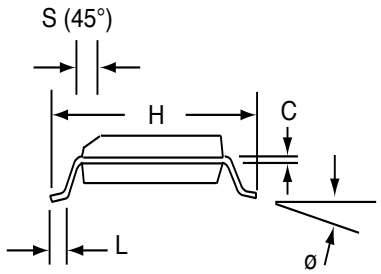
Parameter	Symbol	ALD910021 Min	ALD910021 Typ	ALD910021 Max	Unit	Test Conditions
Gate Threshold Voltage	V_t	2.08	2.10	2.12	V	$V_{GS} = V_{DS}$; $I_{DS(ON)} = 1\mu A$
Offset Voltage	V_{OS}		5	20	mV	$V_{t1} - V_{t2}$
Offset Voltage Tempco	TC_{VOS}		5		μV/C	$V_{t1} - V_{t2}$
Gate Threshold Voltage Tempco	TC_{Vt}		-2.2		mV/C	$V_{GS} = V_{DS}$; $I_{DS(ON)} = 1\mu A$
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.0001 17000		μA MΩ	V_{IN} = 1.70V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.001 1800		μA MΩ	V_{IN} = 1.80V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.01 190		μA MΩ	V_{IN} = 1.90V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		0.1 20		μA MΩ	V_{IN} = 2.00V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		1 2.1		μA MΩ	V_{IN} = 2.10V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		10 0.22		μA MΩ	V_{IN} = 2.20V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		100 0.023		μA MΩ	V_{IN} = 2.32V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		300 0.008		μA MΩ	V_{IN} = 2.40V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		1000 0.003		μA MΩ	V_{IN} = 2.54V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		3000 0.001		μA MΩ	V_{IN} = 2.60V
Output Current Drain Source On Resistance	I_{OUT} $R_{DS(ON)}$		10000 0.0003		μA MΩ	V_{IN} = 3.10V
Drain Source Breakdown Voltage	BV_{DSX}	10.6			V	
Drain Source Leakage Current[1]	$I_{DS(OFF)}$		10	400 4	pA nA	$V_{IN} = V_{GS} = V_{DS} = V_t - 1.0$ $V_{IN} = V_{GS} = V_{DS} = V_t - 1.0$, T_A = +125°C
Gate Leakage Current[1]	I_{GSS}		5	200 1	pA nA	V_{GS} = 5.0V, V_{DS} = 0V V_{GS} = 5.0V, V_{DS} = 0V, T_A = +125°C
Input Capacitance	C_{ISS}		30		pF	V_{GS} = 0V, V_{DS} = 5.0V
Turn-on Delay Time	t_{on}		10		ns	
Turn-off Delay Time	t_{off}		10		ns	
Crosstalk			60		dB	f = 100KHz

SOIC-16 PACKAGE DRAWING

16 Pin Plastic SOIC Package



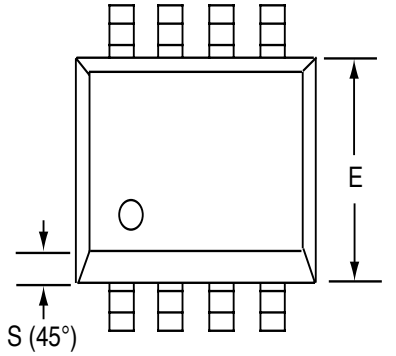


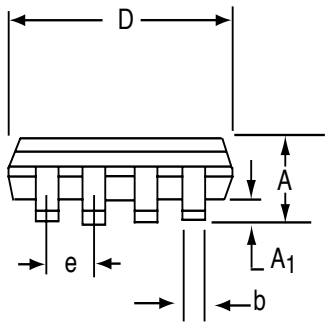


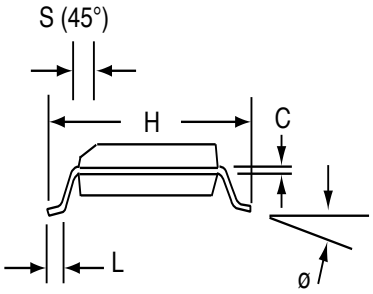
Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A_1	0.10	0.25	0.004	0.010
b	0.35	0.45	0.014	0.018
C	0.18	0.25	0.007	0.010
D-16	9.80	10.00	0.385	0.394
E	3.50	4.05	0.140	0.160
e	1.27 BSC		0.050 BSC	
H	5.70	6.30	0.224	0.248
L	0.60	0.937	0.024	0.037
Ø	0°	8°	0°	8°
S	0.25	0.50	0.010	0.020

SOIC-8 PACKAGE DRAWING

8 Pin Plastic SOIC Package







Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A_1	0.10	0.25	0.004	0.010
b	0.35	0.45	0.014	0.018
C	0.18	0.25	0.007	0.010
D-8	4.69	5.00	0.185	0.196
E	3.50	4.05	0.140	0.160
e	1.27 BSC		0.050 BSC	
H	5.70	6.30	0.224	0.248
L	0.60	0.937	0.024	0.037
Ø	0°	8°	0°	8°
S	0.25	0.50	0.010	0.020

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